

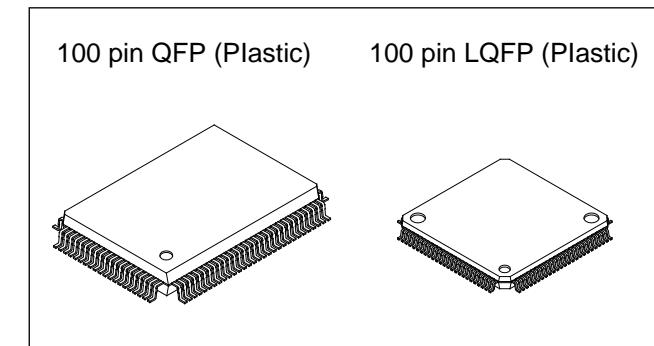
CMOS 8-bit Single Chip Microcomputer**Description**

The CXP81840A/81848A is a CMOS 8-bit microcomputer which consists of A/D converter, serial interface, timer/counter, time base timer, vector interruption, high precision timing pattern generation circuit, PWM generator, PWM for tuner, 32kHz timer/event counter, remote control receiving circuit, as well as basic configurations like 8-bit CPU, ROM, RAM and I/O port. They are integrated into a single chip.

Also CXP81840A/81848A provides sleep/stop function which enables to lower power consumption and ultra-low speed instruction mode in 32kHz operation.

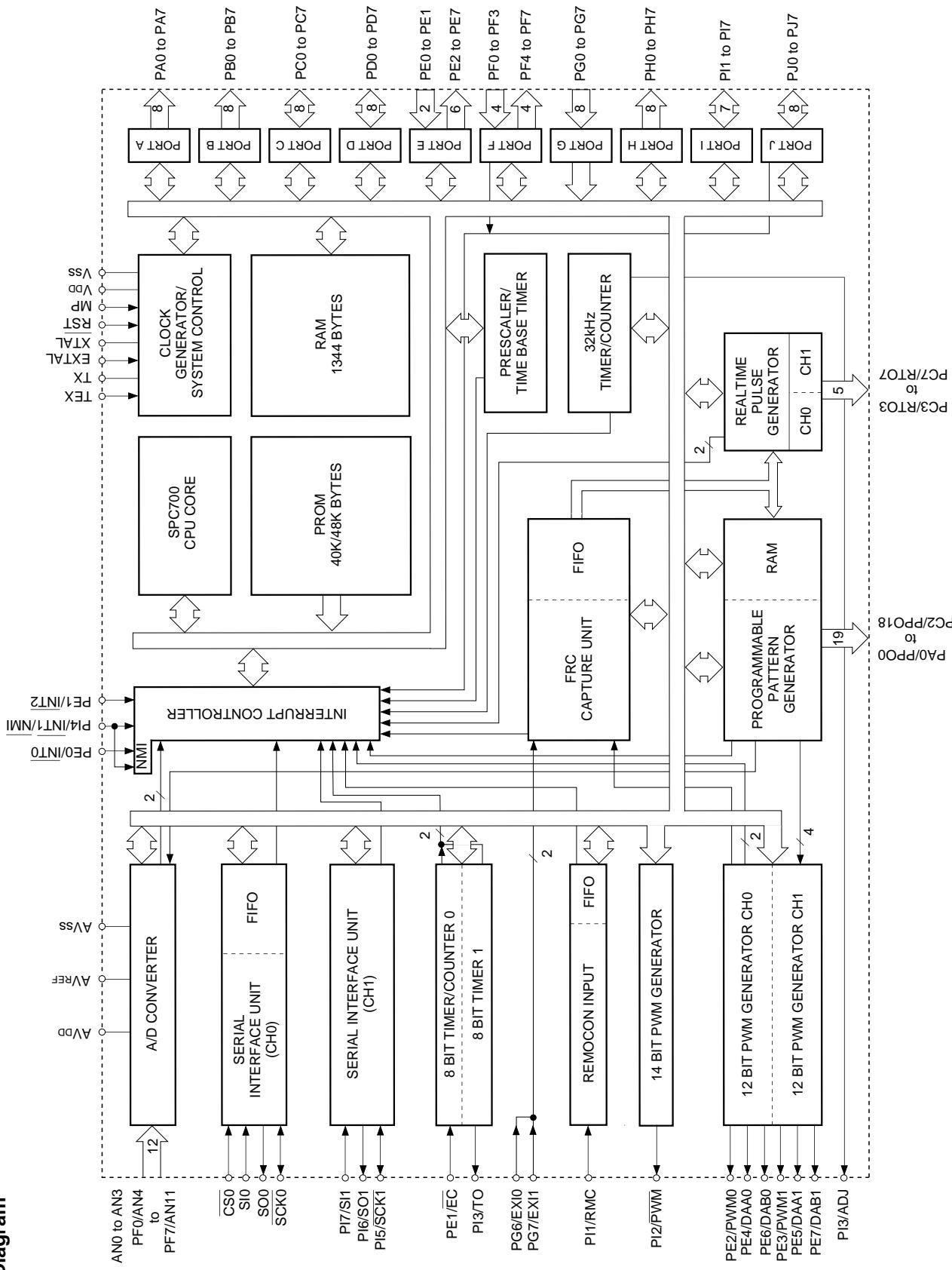
Features

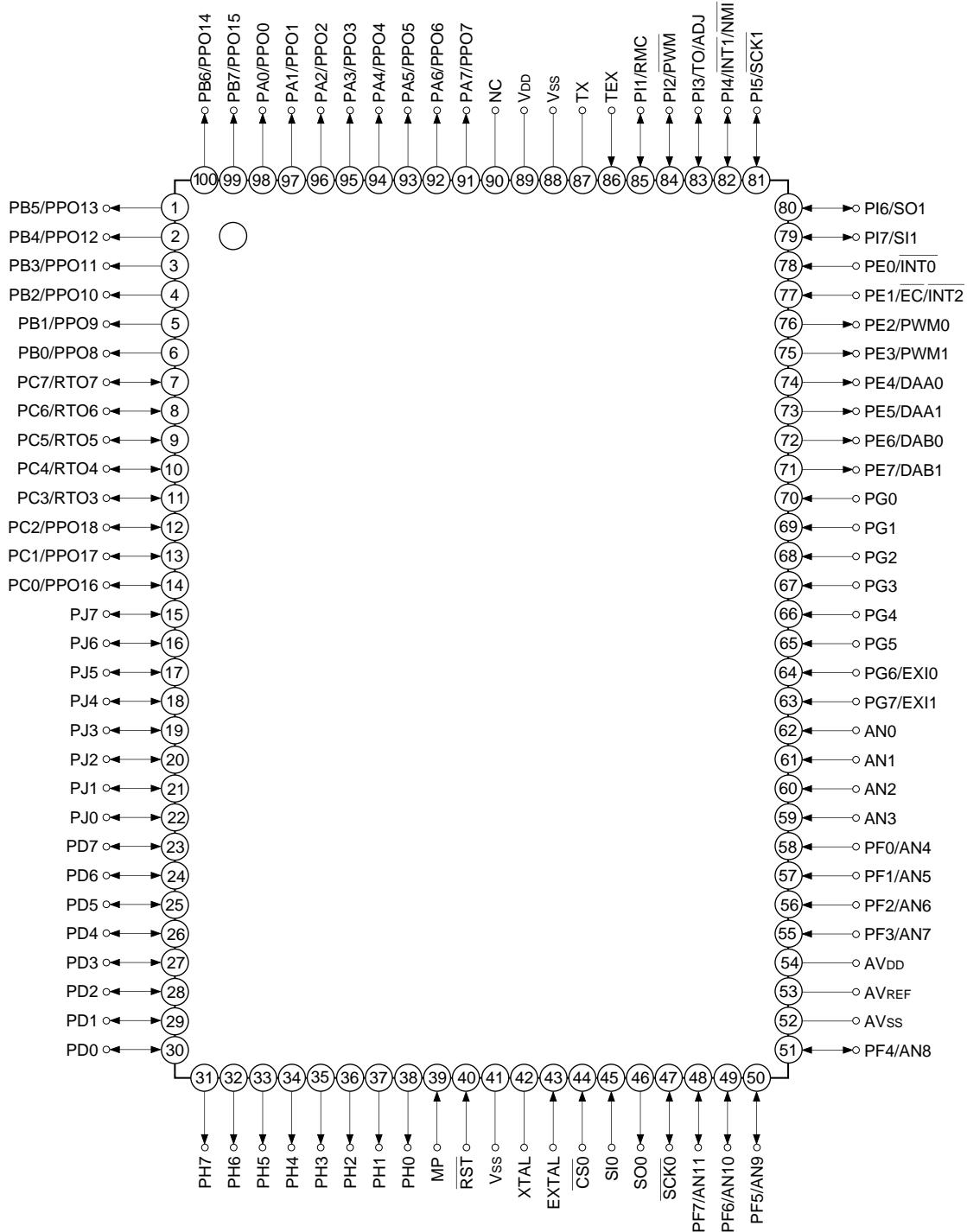
- A wide instruction set (213 instructions) which cover various types of data
 - 16-bit arithmetic instruction/multiplication and division instructions/boolean bit operation instruction
- Minimum instruction cycle
 - During operation 333ns/12MHz (Supply voltage 3.0 to 5.5V)
 - During operation 250ns/16MHz (Supply voltage 4.5 to 5.5V)
 - During operation 122µs/32kHz
- Incorporated ROM capacity
 - 40K bytes (CXP81840A)
 - 48K bytes (CXP81848A)
- Incorporated RAM capacity
 - 1344bytes
- Peripheral functions
 - A/D converter
 - 8-bit, 12-channel, successive approximation system
(Conversion time 20.0µs/16MHz)
 - Serial interface
 - Incorporated 8-bit and 8-stage FIFO, 1-channel
(1 to 8 bytes auto transfer)
 - 8-bit serial I/O, 1-channel
 - Timer
 - 8-bit timer, 8-bit timer/counter, 19-bit time base timer
32kHz timer/counter
 - High precision timing pattern generator
 - PPG 19 pins 32-stage programmable
 - RTG 5-pins 2-channel
 - PWM/DA gate output
 - 12-bit, 2-channel (Repetitive frequency 62kHz/16MHz)
 - FRC capture unit
 - Incorporated 26-bit and 8-stage FIFO
 - PWM output
 - 14-bit, 1-channel
 - Remote control receiving circuit
 - 8-bit pulse measuring counter, 6-stage FIFO
- Interruption
 - 20 factors, 15 vectors, multi-interruption possible
- Standby mode
 - SLEEP/STOP
- Package
 - 100-pin plastic QFP/LQFP
- Piggyback/evaluation chip
 - CXP81800 100-pin ceramic QFP/LQFP

**Structure**

Silicon gate CMOS IC

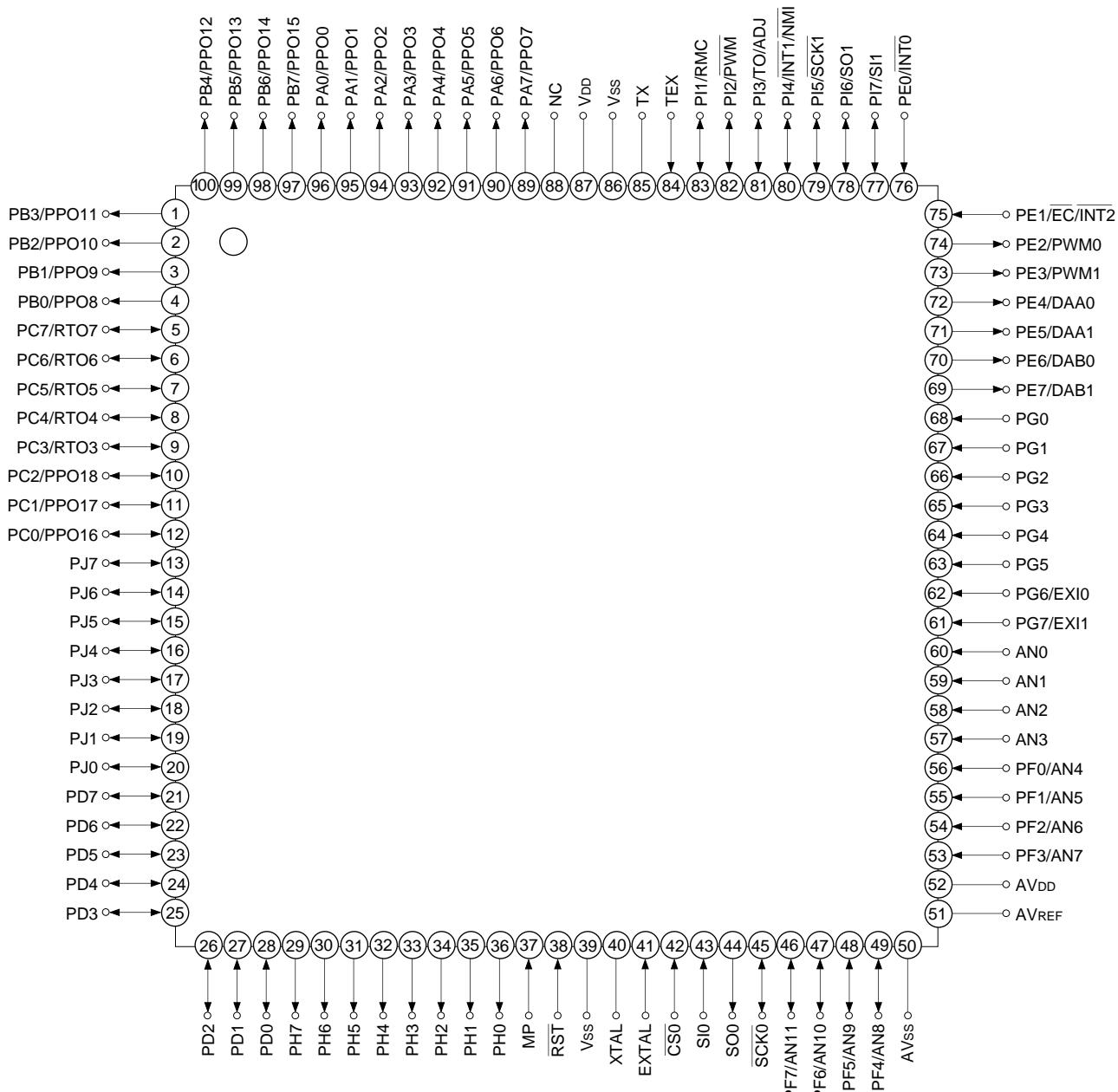
Sony reserves the right to change products and specifications without prior notice. This information does not convey any license by any implication or otherwise under any patents or other right. Application circuits shown, if any, are typical examples illustrating the operation of the devices. Sony cannot assume responsibility for any problems arising out of the use of these circuits.

Block Diagram

Pin Configuration 1 (Top View) 100 pin QFP package


Note)

1. NC (Pin 90) is always connected to VDD.
2. Vss (Pins 41 and 88) are both connected to GND.

Pin Configuration 2 (Top View) 100 pin LQFP package

Note) 1. NC (Pin 88) is always connected to VDD.
 2. Vss (Pins 39 and 86) are both connected to GND.

Pin Description

Symbol	I/O	Description	
PA0/PPO0 to PA7/PPO7	Output/ Real time Output	(Port A) 8-bit output port. Data is gated with PPO contents by OR-gate and they are output. (8 pins)	Programmable pattern generator (PPG) output. Functions as high precision real time pulse output port. (19 pins)
PB0/PPO8 to PB7/PPO15	Output/ Real time Output	(Port B) 8-bit output port. Data is gated with PPO contents by OR-gate and they are output. (8 pins)	
PC0/PPO16 to PC2/PPO18	I/O/ Real time Output	(Port C) 8-bit I/O port, enables to specify I/O by bit unit. Data is gated with PPO or RTO contents by OR-gate and they are output. (8 pins)	
PC3/RTO3 to PC7/RTO7	I/O/ Real time Output	(Port C) 8-bit I/O port, enables to specify I/O by bit unit. Data is gated with PPO or RTO contents by OR-gate and they are output. (8 pins)	Real time pulse generator (RTG) output. Functions as high precision real time pulse output port. (5 pins)
PD0 to PD7	I/O	(Port D) 8-bit I/O port. Enable to specify I/O by 4-bit unit. Enables to drive 12mA sink current. (8 pins)	
PE0/INT0	Input/input	(Port E) 8-bit port. Lower 2 bits are input pins and upper 6 bits are output pins. (8 pins)	Input pin to request external interruption. Active when falling edge.
PE1/EC/INT2	Input/input/input		External event input pin for timer/counter. Input pin to request external interruption. Active when falling edge.
PE2/PWM0	Output/output		PWM output pins. (2 pins)
PE3/PWM1	Output/output		
PE4/DAA0	Output/output		
PE5/DAA1	Output/output		
PE6/DAB0	Output/output		DA gate pulse output pins. (4 pins)
PE7/DAB1	Output/output		
AN0 to AN3	Input	Analog input pins to A/D converter. (12 pins)	
PF0/AN4 to PF3/AN7	Input/input	(Port F) Lower 4 bits are input port and upper 4 bits are output port. Lower 4 bits also serve as standby release input pin. (8 pins)	
PF4/AN8 to PF7/AN11	Output/input		
SCK0	I/O	Serial clock (CH0) I/O pin.	
SO0	Ouput	Serial data (CH0) output pin.	
SI0	Input	Serial data (CH0) input pin.	
CS0	Input	Serial chip select (CH0) input pin.	

Symbol	I/O	Description	
PG0 to PG5	Input	(Port G) 8-bit input port. (8 pins)	
PG6/EXI0	Input/input		
PG7/EXI1	Input/input		External input pin to FRC capture unit.
PH0 to PH7	Output	(Port H) N-ch open drain output of middle tension proof (12V) and high current (12mA). (8 pins)	
PI1/RMC	I/O/input	(Port I) 7-bit I/O port. I/O port can be specified by the bit unit. (7 pins)	Remote control receiving circuit input pin.
PI2/PWM	I/O/output		14-bit PWM output pin.
PI3/TO/ADJ	I/O/output/output		Timer/counter, 32kHz oscillation adjustment output pin.
PI4/INT1/ NMI	I/O/input/input		Input pin to request external interruption and non maskable interruption. Active when falling edge.
PI5/SCK1	I/O/I/O		Serial clock (CH1) I/O pin.
PI6/SO1	I/O/output		Serial data (CH1) output pin.
PI7/SI1	I/O/input		Serial data (CH1) input pin.
PJ0 to PJ7	I/O	(Port J) 8-bit I/O port. Function as standby release input can be specified by the bit unit. I/O can be specified by the bit unit.	
EXTAL	Input		Connecting pin of crystal oscillator for system clock. When supplying the external clock, input the external clock to EXTAL pin and input opposite phase clock to XTAL pin.
XTAL	Output		
TEX	Input		Connecting pin of crystal oscillator for 32kHz timer clock. When used as event counter, input to TEX pin and leave TX pin open. (Feedback resistor is not removed.)
TX	Output		
RST	Input	System reset pin of active "Low" level.	
MP	Input	Microprocessor mode input pin. Always connect to GND.	
AVDD		Positive power supply pin of A/D converter.	
AVREF	Input	Reference voltage input pin of A/D converter.	
AVss		GND pin of A/D converter.	
VDD		Positive power supply pin.	
Vss		GND pin. Connect both Vss pins to GND.	

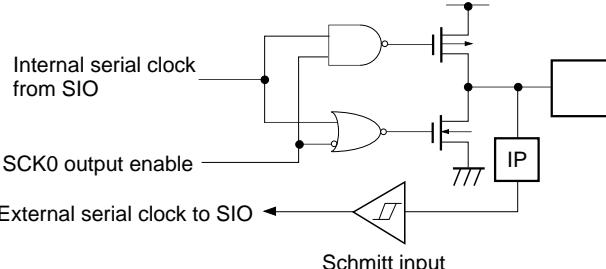
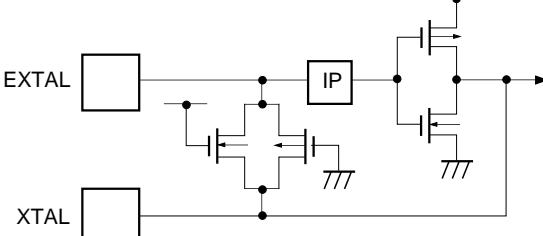
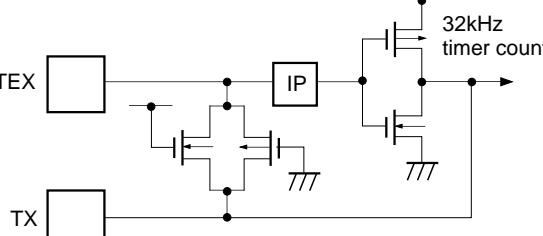
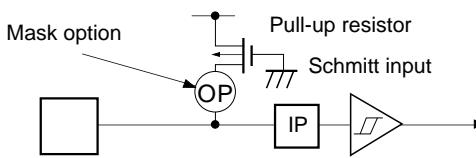
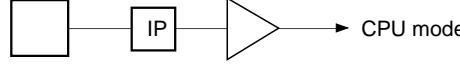
Input/Output Circuit Formats for Pins

Pin	Circuit format	When reset
PA0/PPO0 to PA7/PPO7 PB0/PPO8 to PB7/PPO15 16 pins	<p>Port A</p> <p>Port B</p> <p>PPO data</p> <p>Port A or Port B</p> <p>Data bus</p> <p>RD</p> <p>Output becomes active from high impedance by data writing to port register.</p>	Hi-Z
PC0/PPO16 to PC2/PPO18 PC3/RTO3 to PC7/RTO7 8 pins	<p>Port C</p> <p>PPO, RTO data</p> <p>Port C data</p> <p>Port C direction</p> <p>Data bus</p> <p>RD (Port C)</p> <p>(Every bit)</p> <p>Input protection circuit</p>	Hi-Z
PD0 to PD7 8 pins	<p>Port D</p> <p>Port D data</p> <p>Port D direction</p> <p>Data bus</p> <p>RD (Port D)</p> <p>(Every 4 bits) (PD0 to 3) (PD4 to 7)</p> <p>High current 12mA</p>	Hi-Z

Pin	Circuit format	When reset
PE0/INT0 PE1/EC/INT2 2 pins	<p>Port E</p> <p>Schmitt input</p> <p>RD (Port E)</p>	Hi-Z
PE2/PWM0 PE3/PWM1 PE4/DAA0 PE5/DAA1 4 pins	<p>Port E</p> <p>DA gate output or PWM output</p> <p>Hi-Z control</p> <p>Port E data</p> <p>Port/DA output select</p> <p>Data bus</p> <p>RD (Port E)</p>	Hi-Z
PE6/DAB0 PE7/DAB1 2 pins	<p>Port E</p> <p>DA gate output</p> <p>Hi-Z control</p> <p>Port E data</p> <p>Port/DA output select</p> <p>Data bus</p> <p>RD (Port E)</p>	H level
AN0 to AN3 4 pins	<p>Input multiplexer</p> <p>A/D converter</p>	Hi-Z
PF0/AN4 to PF3/AN7 4 pins	<p>Port F</p> <p>Input multiplexer</p> <p>A/D converter</p> <p>RD (Port F)</p>	Hi-Z

Pin	Circuit format	When reset
PF4/AN8 to PF7/AN11 4 pins	<p>Port F</p> <p>Port F data → RD (Port F) → Port F selection → Multiplexer → IP → A/D converter → Data bus.</p> <p>RD (Port F) is controlled by Port F selection.</p> <p>IP is an inverter.</p> <p>A/D converter is a square symbol.</p> <p>Multiplexer is a hexagonal symbol.</p>	Hi-Z
PG0 to PG5 6 pins	<p>Port G</p> <p>Schmitt input → IP → Inverter → Data bus.</p> <p>RD (Port G) is controlled by the output of the inverter.</p> <p>Note: For PG4 and PG5, CMOS schmitt input or TTL schmitt input can be selected with the mask option.</p>	Hi-Z
PG6/EXI0 PG7/EXI1 2 pins	<p>Port G</p> <p>IP → Inverter → FRC capture unit → Data bus.</p> <p>RD (Port G) is controlled by the output of the inverter.</p>	Hi-Z
PH0 to PH7 8 pins	<p>Port H</p> <p>Port H data → IP → Inverter → RD (Port H).</p> <p>Middle tension proof 12V → High current 12mA.</p>	Hi-Z
PI2/PWM PI3/TO/ADJ 2 pins	<p>Port I</p> <p>Port I selection → MPX → IP → Inverter → RD (Port I).</p> <p>PI2: From 14-bit PWM</p> <p>PI3: (From timer/counter, 32kHz timer)</p> <p>Port I data → Port I I/O direction → MPX.</p> <p>Data bus ← RD (Port I).</p>	Hi-Z

PIn	Circuit format	When reset
PI1/RMC PI4/INT1/NMI PI7/SI1 3 pins	<p>Port I</p> <p>PI1: To remote control circuit PI4: To interruption circuit PI7: To serial CH1</p>	Hi-Z
PI5/SCK1 PI6/SO1 2 pins	<p>Port I</p> <p>Note) (PI5 is schmitt input (PI6 is inverter input)</p>	Hi-Z
PJ0 to PJ7 8 pins	<p>Port J</p> <p>Edge detection Standby release</p>	Hi-Z
CS0 SI0 2 pins	<p>Schmitt input To SIO</p>	Hi-Z
SO0 1 pin	<p>SO0 from SIO SO0 output enable</p>	Hi-Z

Pin	Circuit format	When reset
SCK0 1 pin	 <p>Internal serial clock from SIO SCK0 output enable External serial clock to SIO Schmitt input</p>	Hi-Z
EXTAL XTAL 2 pins	 <ul style="list-style-type: none"> Shows the circuit composition during oscillation. Feedback resistor is removed during stop. XTAL becomes "H" level. 	Oscillation
TEX TX 2 pins	 <ul style="list-style-type: none"> Shows the circuit composition during oscillation. Feedback resistor is removed during 32kHz oscillation circuit stop by software. At this time TEX pin outputs "L" level and TX pin outputs "H" level. 	Oscillation
RST 1 pin	 <p>Mask option Pull-up resistor Schmitt input IP</p>	L level
MP 1 pin	 <p>IP CPU mode</p>	Hi-Z

Absolute Maximum Ratings

(Vss = 0V)

Item	Symbol	Rating	Unit	Remarks
Supply voltage	V _{DD}	−0.3 to +7.0	V	
	AV _{DD}	AV _{ss} to +7.0 ^{*1}	V	
	AV _{ss}	−0.3 to +0.3	V	
Input voltage	V _{IN}	−0.3 to +7.0 ^{*2}	V	
Output voltage	V _{OUT}	−0.3 to +7.0 ^{*2}	V	
Medium withstand output voltage	V _{OUTP}	−0.3 to +15.0	V	PH pin
High level output current	I _{OH}	−5	mA	
High level total output current	ΣI _{OH}	−50	mA	Total of output pins
Low level output current	I _{OL}	15	mA	Other than high current output pins: per pin
	I _{OLC}	20	mA	High current port pin ^{*3} : per pin
Low level total output current	ΣI _{OL}	130	mA	Total of output pins
Operating temperature	T _{opr}	−20 to +75	°C	
Storage temperature	T _{stg}	−55 to +150	°C	
Allowable power dissipation	P _D	600	mW	QFP package type
		380		LQFP package type

^{*1} AV_{DD} and V_{DD} should be set to a same voltage.^{*2} V_{IN} and V_{OUT} should not exceed V_{DD} + 0.3V.^{*3} The high current operation transistors are the N-CH transistors of the PD and PH ports.

Note) Usage exceeding absolute maximum ratings may permanently impair the LSI. Normal operation should better take place under the recommended operating conditions. Exceeding those conditions may adversely affect the reliability of the LSI.

Recommended Operating Conditions

(Vss = 0V)

Item	Symbol	Min.	Max.	Unit	Remarks
Supply voltage	VDD	4.5	5.5	V	fc = less than 16MHz
		3.0	5.5		fc = less than 12MHz
		2.7	5.5	V	Guaranteed range during low speed mode (1/16 dividing clock) operation
		2.7	5.5	V	Guaranteed operation range by TEX clock
		2.5	5.5	V	Guaranteed data hold operation range during STOP
Analog power supply	AVDD	3.0	5.5	V	*1
High level input voltage	VIH	0.7VDD	VDD	V	*2
	VIHS	0.8VDD	VDD	V	CMOS schmitt input*3
	VIHTS	2.2	VDD	V	TTL schmitt input*4, *7
	VIHEX	VDD - 0.4	VDD + 0.3	V	EXTAL pin*5, *7 TEX pin*6, *7
		VDD - 0.2	VDD + 0.2	V	EXTAL pin*5, *8 TEX pin*6, *8
Low level input voltage	VIL	0	0.3VDD	V	*2, *7
		0	0.2VDD	V	*2, *8
	VILS	0	0.2VDD	V	CMOS schmitt input*3
	VILTS	0	0.8	V	TTL schmitt input*4, *7
	VILEX	-0.3	0.4	V	EXTAL pin*5, *7 TEX pin*6, *7
		-0.3	0.2	V	EXTAL pin*5, *8 TEX pin*6, *8
Operating temperature	Topr	-20	+75	°C	

*1 AVDD and VDD should be set to a same voltage.

*2 Normal input port (each pin of PC, PD, PE0, PE1, PF0 to PF3, PG, PI and PJ), MP pin.

*3 Each pin of CS0, SI0, SCK0, RST, PE0/INT0, PE1/EC/INT2, PG (For PG4 and PG5, when CMOS schmitt input is selected with mask option), PI1/RMC, PI4/INT1/NMI, PI5/SCK1 and PI7/SI1.

*4 Each pin of PG4 and PG5 (When TTL schmitt input is selected with mask option)

*5 It specifies only when the external clock is input.

*6 It specifies only when the event count clock is input.

*7 This case applies to the range of 4.5 to 5.5V supply voltage (VDD).

*8 This case applies to the range of 3.0 to 3.6V supply voltage (VDD).

Electrical Characteristics**DC Characteristics** ($V_{DD} = 4.5$ to $5.5V$)

(Ta = -20 to +75°C, Vss = 0V)

Item	Symbol	Pins	Conditions	Min.	Typ.	Max.	Unit
High level output voltage	V _{OH}	PA to PD, PE2 to PE7, PF4 to PF7, PH (V _{OL} only) PI1 to PI7 PJ, S00, SCK0	V _{DD} = 4.5V, I _{OH} = -0.5mA	4.0			V
			V _{DD} = 4.5V, I _{OH} = -1.2mA	3.5			V
Low level output voltage	V _{OL}	V _{OL}	V _{DD} = 4.5V, I _{OL} = 1.8mA			0.4	V
			V _{DD} = 4.5V, I _{OL} = 3.6mA			0.6	V
		PD, PH	V _{DD} = 4.5V, I _{OL} = 12.0mA			1.5	V
Input current	I _{IHE}	EXTAL	V _{DD} = 5.5V, V _{IH} = 5.5V	0.5		40	μA
	I _{IIE}		V _{DD} = 5.5V, V _{IL} = 0.4V	-0.5		-40	μA
	I _{IHT}	TEX	V _{DD} = 5.5V, V _{IH} = 5.5V	0.1		10	μA
	I _{IIT}		V _{DD} = 5.5V, V _{IL} = 0.4V	-0.1		-10	μA
	I _{ILR}	RST*1		-1.5		-400	μA
I/O leakage current	I _{Iz}	PA to PG, PI, PJ, MP AN0 to AN3, CS0, SI0, SO0 SCK0, RST*1	V _{DD} = 5.5V, V _I = 0, 5.5V			±10	μA
Open drain output leakage current (N-CH Tr OFF in state)	I _{LOH}	PH	V _{DD} = 5.5V V _{OH} = 12V			50	μA
Supply current*2	I _{DD1}	V _{DD}	16MHz crystal oscillation (C ₁ = C ₂ = 15pF) V _{DD} = 5V ± 0.5V*3		24	45	mA
	I _{DDS1}		SLEEP mode V _{DD} = 5V ± 0.5V		1.3	8	mA
	I _{DD2}		32kHz crystal oscillation (C ₁ = C ₂ = 47pF) V _{DD} = 3V ± 0.3V		35	100	μA
	I _{DDS2}		SLEEP mode V _{DD} = 3V ± 0.3V		6	30	μA
	I _{DDS3}		STOP mode (EXTAL and TEX pins oscillation stop) V _{DD} = 5V ± 0.5V			10	μA
Input capacity	C _{IN}	Other than V _{DD} , V _{SS} , AV _{DD} , and AV _{SS}	Clock 1MHz 0V other than the measured pins		10	20	pF

*1 RST pin specifies the input current when the pull-up resistor is selected, and specifies leakage current when non-resistor is selected.

*2 When entire output pins are open.

*3 When setting upper 2 bits (CPU clock selection) of clock control register CLC (address: 00FEH) to "00" and operating in high speed mode (1/2 dividing clock).

DC Characteristics ($V_{DD} = 3.0$ to $3.6V$)

(Ta = -20 to +75°C, Vss = 0V)

Item	Symbol	Pins	Conditions	Min.	Typ.	Max.	Unit
High level output voltage	V _{OH}	PA to PD, PE2 to PE7, PF4 to PF7, PH (Vol only) PI1 to PI7 PJ, SO0, SCK0	V _{DD} = 3.0V, I _{OH} = -0.15mA	2.7			V
			V _{DD} = 3.0V, I _{OH} = -0.5mA	2.3			V
Low level output voltage	V _{OL}	PD, PH	V _{DD} = 3.0V, I _{OL} = 1.2mA			0.3	V
			V _{DD} = 3.0V, I _{OL} = 1.6mA			0.5	V
Input current	I _{IHE}	EXTAL	V _{DD} = 3.6V, V _{IH} = 3.6V	0.3		20	μA
	I _{IIE}		V _{DD} = 3.6V, V _{IL} = 0.3V	-0.3		-20	μA
	I _{IHT}	TEX	V _{DD} = 3.6V, V _{IH} = 3.6V	0.1		10	μA
	I _{ILT}		V _{DD} = 3.6V, V _{IL} = 0.3V	-0.1		-10	μA
	I _{ILR}	RST*1		-0.9		-200	μA
I/O leakage current	I _{Iz}	PA to PG, PI, PJ, MP AN0 to AN3, CS0, SI0, SO0 SCK0, RST*1	V _{DD} = 3.6V, VI = 0, 3.6V			±10	μA
Open drain output leakage current	I _{LOH}	PH	V _{DD} = 3.6V, V _{OH} = 12V			50	μA
Supply current*2	I _{DD1}	V _{DD}	12MHz crystal oscillation (C ₁ = C ₂ = 15pF) V _{DD} = 3.3V ± 0.3V*3		11	25	mA
	I _{DDS1}		SLEEP mode V _{DD} = 3.3V ± 0.3V		0.5	2.5	mA
	I _{DDS3}		STOP mode (EXTAL and TEX pins oscillation stop) V _{DD} = 3.3V ± 0.3V			10	μA
Input capacity	C _{IN}	Other than V _{DD} , V _{SS} , AV _{DD} , and AV _{SS}	Clock 1MHz 0V other than the measured pins		10	20	pF

*1 RST pin specifies the input current when the pull-up resistor is selected, and specifies leakage current when non-resistor is selected.

*2 When entire output pins are open.

*3 When setting upper 2 bits (CPU clock selection) of clock control register CLC (address: 00FEH) to "00" and operating in high speed mode (1/2 dividing clock).

AC Characteristics**(1) Clock timing**

(Ta = -20 to +75°C, VDD = 3.0 to 5.5V, Vss = 0V)

Item	Symbol	Pins	Conditions	Min.	Max.	Unit	
System clock frequency	fc	XTAL EXTAL	Fig. 1, Fig. 2	VDD = 4.5 to 5.5V	1	16	MHz
					1	12	
System clock input pulse width	t _{XL} , t _{XH}	EXTAL	Fig. 1, Fig. 2 (External clock drive)	VDD = 4.5 to 5.5V	28		ns
					37.5		
System clock input rise and fall times	t _{CR} , t _{CF}	EXTAL	Fig. 1, Fig. 2 (External clock drive)		200	ns	
Event count clock input pulse width	t _{EH} , t _{EL}	EC	Fig. 3		t _{sys} × 4*	ns	
Event count clock input rise and fall times	t _{ER} , t _{EF}	EC	Fig. 3		20	ns	
System clock frequency	fc	TEX TX	Fig. 2 VDD = 2.7 to 5.5V (32kHz clock applied condition)	32.768		kHz	
Event count clock input pulse width	t _{TL} , t _{TH}	TEX	Fig. 3	10		μs	
Event count clock input rise and fall times	t _{TR} , t _{TF}	TEX	Fig. 3		20	ms	

* t_{sys} indicates three values according to the contents of the clock control register (address; 00FEH) upper 2 bits (CPU clock selection).

t_{sys} [ns] = 2000/fc (Upper 2-bit = "00"), 4000/fc (Upper 2-bit = "01"), 16000/fc (Upper 2-bit = "11")

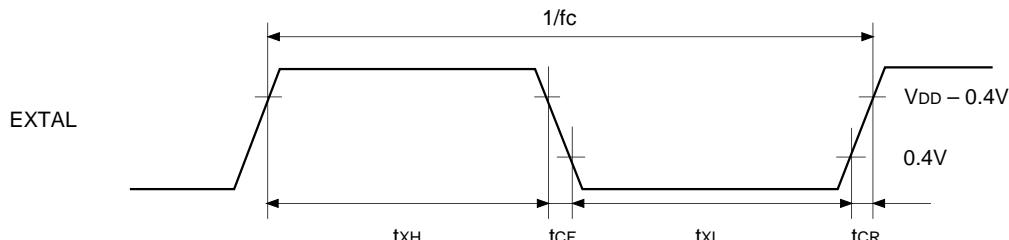
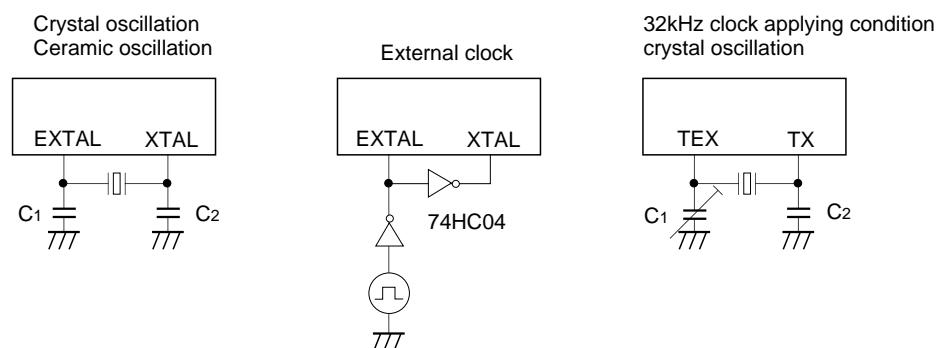
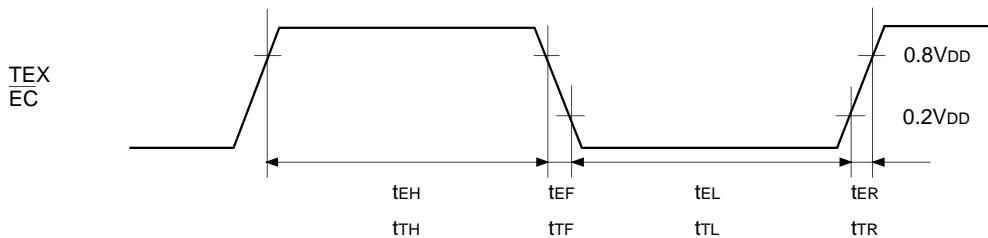
Fig. 1. Clock timing**Fig. 2. Clock applied condition**

Fig. 3. Event count clock timing**(2) Serial transfer (CH0)**

(Ta = -20 to +75°C, VDD = 4.5 to 5.5V, Vss = 0V)

Item	Symbol	Pin	Condition	Min.	Max.	Unit
CS0 ↓ → SCK0 delay time	tDCSK	SCK0	Chip select transfer mode (SCK0 = output mode)		t _{sys} + 200	ns
CS0 ↑ → SCK0 floating delay time	tDCSKF	SCK0	Chip select transfer mode (SCK0 = output mode)		t _{sys} + 200	ns
CS0 ↓ → SO0 delay time	tDCSO	SO0	Chip select transfer mode		t _{sys} + 200	ns
CS0 ↑ → SO0 floating delay time	tDCSOF	SO0	Chip select transfer mode		t _{sys} + 200	ns
CS0 high level width	tWHCS	CS0	Chip select transfer mode	t _{sys} + 200		ns
SCK0 cycle time	tKCY	SCK0	Input mode	2t _{sys} + 200		ns
			Output mode	16000/fc		ns
SCK0 high and low level widths	tKH tKL	SCK0	Input mode	t _{sys} + 100		ns
			Output mode	8000/fc - 50		ns
SI0 input setup time (against SCK0 ↑)	tSIK	SI0	SCK0 input mode	100		ns
			SCK0 output mode	200		ns
SI0 input hold time (against SCK0 ↑)	tKSI	SI0	SCK0 input mode	t _{sys} + 200		ns
			SCK0 output mode	100		ns
SCK0 ↓ → SO0 delay time	tKSO	SO0	SCK0 input mode		t _{sys} + 200	ns
			SCK0 output mode		100	ns

Note 1) t_{sys} indicates three values according to the contents of the clock control register (address; 00FEH)
upper 2 bits (CPU clock selection).

t_{sys} [ns] = 2000/fc (Upper 2-bit = "00"), 4000/fc (Upper 2-bit = "01"), 16000/fc (Upper 2-bit = "11")

Note 2) The load of SCK0 output mode and SO0 output delay time is 50pF + 1TTL.

Serial transfer (CH0)

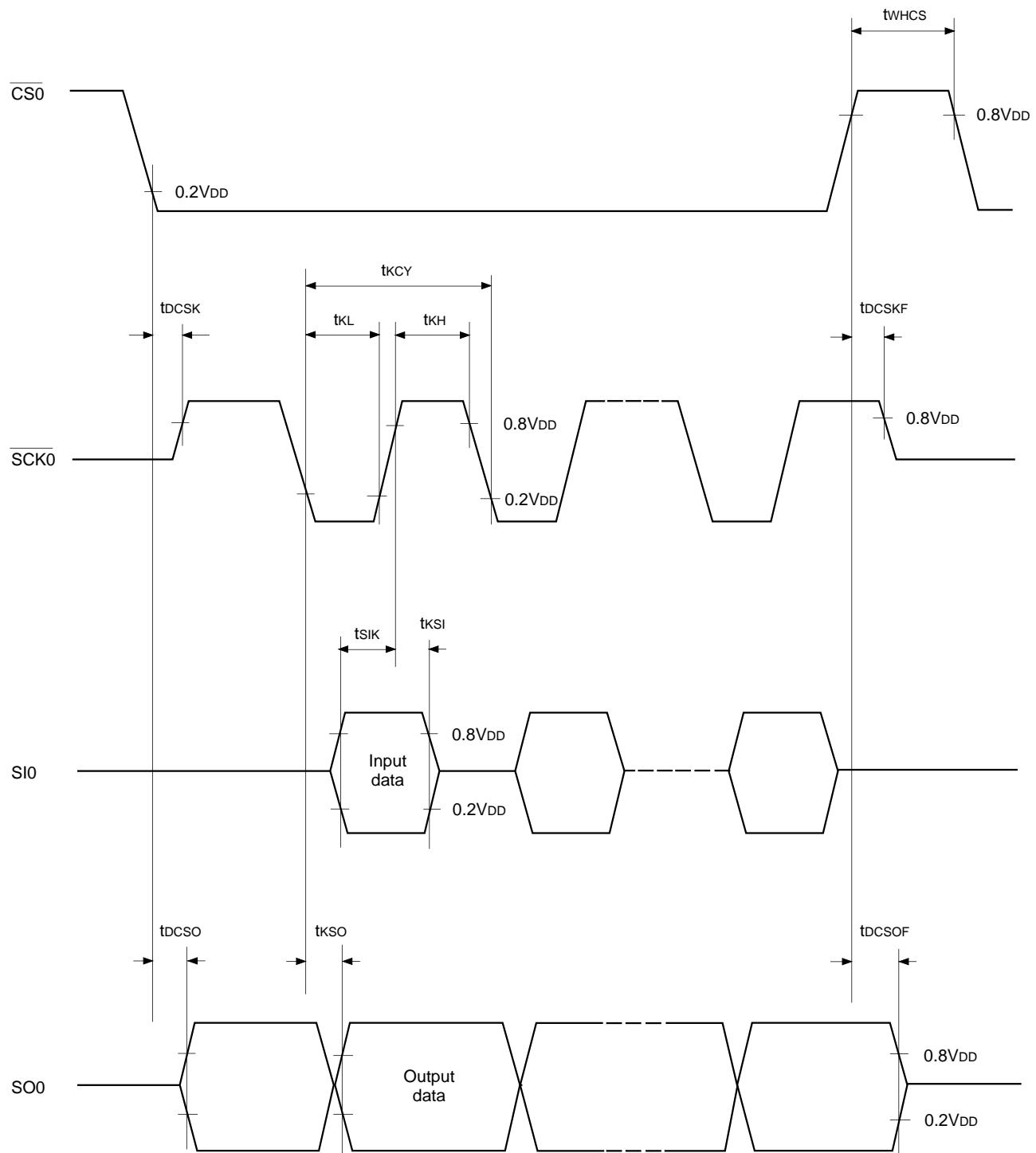
(Ta = -20 to +75°C, VDD = 3.0 to 3.6V, Vss = 0V)

Item	Symbol	Pin	Condition	Min.	Max.	Unit
CS0 ↓ → SCK0 delay time	tDCSK	SCK0	Chip select transfer mode (SCK0 = output mode)		tsys + 250	ns
CS0 ↑ → SCK0 floating delay time	tDCSKF	SCK0	Chip select transfer mode (SCK0 = output mode)		tsys + 200	ns
CS0 ↓ → SO0 delay time	tDCSO	SO0	Chip select transfer mode		tsys + 250	ns
CS0 ↑ → SO0 floating delay time	tDCSOF	SO0	Chip select transfer mode		tsys + 200	ns
CS0 high level width	tWHCS	SCK0	Chip select transfer mode	tsys + 200		ns
SCK0 cycle time	tkCY	SCK0	Input mode	2tsys + 200		ns
			Output mode	16000/fc		ns
SCK0 high and low level widths	tkH tkL	SCK0	Input mode	tsys + 100		ns
			Output mode	8000/fc - 100		ns
SI0 input setup time (against SCK0 ↑)	tsIK	SI0	SCK0 input mode	100		ns
			SCK0 output mode	200		ns
SI0 input hold time (against SCK0 ↑)	tksi	SI0	SCK0 input mode	tsys + 200		ns
			SCK0 output mode	100		ns
SCK0 ↓ → SO0 delay time	tkso	SO0	SCK0 input mode		tsys + 250	ns
			SCK0 output mode		100	ns

Note 1) tsys indicates three values according to the contents of the clock control register (address; 00FEH) upper 2 bits (CPU clock selection).

tsys [ns] = 2000/fc (Upper 2-bit = "00"), 4000/fc (Upper 2-bit = "01"), 16000/fc (Upper 2-bit = "11")

Note 2) The load of SCK0 output mode and SO0 output delay time is 50pF.

Fig. 4. Serial transfer CH0 timing

Serial transfer (CH1)

(Ta = -20 to +75°C, VDD = 4.5 to 5.5V, Vss = 0V)

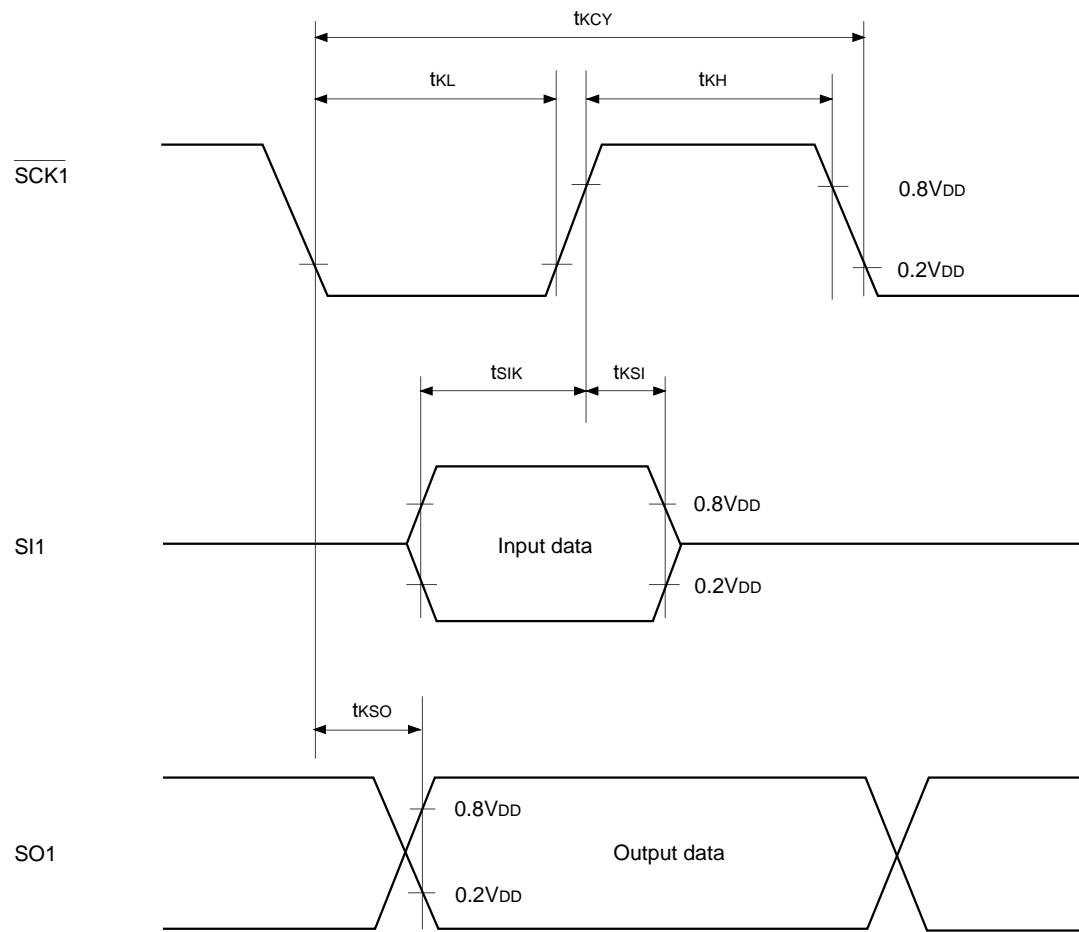
Item	Symbol	Pins	Conditions	Min.	Max.	Unit
<u>SCK1</u> cycle time	t _{KCY}	<u>SCK1</u>	Input mode	1000		ns
			Output mode	16000/fc		ns
SCK1 high and low level widths	t _{KH} t _{KL}	<u>SCK1</u>	Input mode	400		ns
			Output mode	8000/fc – 50		ns
SI1 input setup time (against SCK1 ↑)	t _{SIK}	SI1	<u>SCK1</u> input mode	100		ns
			<u>SCK1</u> output mode	200		ns
SI1 input hold time (against SCK1 ↑)	t _{KSI}	SI1	<u>SCK1</u> input mode	200		ns
			<u>SCK1</u> output mode	100		ns
<u>SCK1</u> ↓ → SO1 delay time	t _{KSO}	SO1	<u>SCK1</u> input mode		200	ns
			<u>SCK1</u> output mode		100	ns

Note) The load of SCK1 output mode and SO1 output delay time is 50pF + 1TTL.**Serial transfer (CH1)**

(Ta = -20 to +75°C, VDD = 3.0 to 3.6V, Vss = 0V)

Item	Symbol	Pins	Conditions	Min.	Max.	Unit
<u>SCK1</u> cycle time	t _{KCY}	<u>SCK1</u>	Input mode	1000		ns
			Output mode	16000/fc		ns
SCK1 high and low level widths	t _{KH} t _{KL}	<u>SCK1</u>	Input mode	400		ns
			Output mode	8000/fc – 100		ns
SI1 input setup time (against SCK1 ↑)	t _{SIK}	SI1	<u>SCK1</u> input mode	100		ns
			<u>SCK1</u> output mode	200		ns
SI1 input hold time (against SCK1 ↑)	t _{KSI}	SI1	<u>SCK1</u> input mode	200		ns
			<u>SCK1</u> output mode	100		ns
<u>SCK1</u> ↓ → SO1 delay time	t _{KSO}	SO1	<u>SCK1</u> input mode		250	ns
			<u>SCK1</u> output mode		100	ns

Note) The load of SCK1 output mode and SO1 output delay time is 50pF.

Fig. 5. Serial transfer CH1 timing

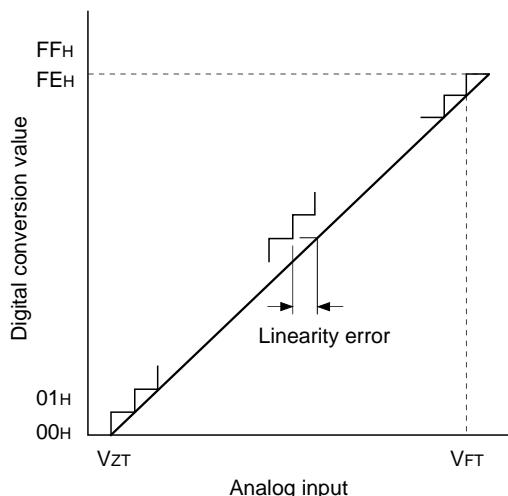
(3) A/D converter characteristics (Ta = -20 to +75°C, VDD = AVDD = 4.5 to 5.5V, AVREF = 4.0 to AVDD, VSS = AVss = 0V)

Item	Symbol	Pins	Conditions	Min.	Typ.	Max.	Unit
Resolution						8	Bits
Linearity error			Ta = 25°C VDD = AVDD = AVREF = 5.0V			±1	LSB
Absolute error			VSS = AVss = 0V			±2	LSB
Conversion time	tCONV			160/fADC*			μs
Sampling time	tSAMP			12/fADC*			μs
Reference input voltage	VREF	AVREF	VDD = AVDD = 4.5 to 5.5V	AVDD - 0.5		AVDD	V
Analog input voltage	VIAN	AN0 to AN11		0			V
AVREF current	IREF	AVREF	Operating mode		0.6	1.0	mA
	IREFS		SLEEP mode STOP mode 32kHz operating mode			10	μA

(Ta = -20 to +75°C, VDD = AVDD = 3.0 to 3.6V, AVREF = 2.7 to AVDD, VSS = AVss = 0V)

Item	Symbol	Pins	Conditions	Min.	Typ.	Max.	Unit
Resolution						8	Bits
Linearity error			Ta = 25°C VDD = AVDD = AVREF = 3.3V			±1	LSB
Absolute error			VSS = AVss = 0V			±2	LSB
Conversion time	tCONV			160/fADC*			μs
Sampling time	tSAMP			12/fADC*			μs
Reference input voltage	VREF	AVREF	VDD = AVDD = 3.0 to 3.6V	AVDD - 0.3		AVDD	V
Analog input voltage	VIAN	AN0 to AN11		0			V
AVREF current	IREF	AVREF	Operating mode		0.4	0.7	mA
	IREFS		SLEEP mode STOP mode 32kHz operating mode			10	μA

Fig. 6. Definitions of A/D converter terms



* The value of fADC is as follows by selecting ADC operation clock (MSC: Address 01FFH bit 0).

When PS2 is selected, fADC = fc/2

When PS1 is selected, fADC = fc

(4) Interruption, reset input

(Ta = -20 to +75°C, VDD = 3.0 to 5.5V, Vss = 0V)

Item	Symbol	Pin	Condition	Min.	Max.	Unit
External interruption high and low level widths	tIH tIL	INT0 INT1 INT2 NMI PJ0 to PJ7		1		μs
Reset input low level width	tRSL	RST		32/fc		μs

Fig. 7. Interruption input timing

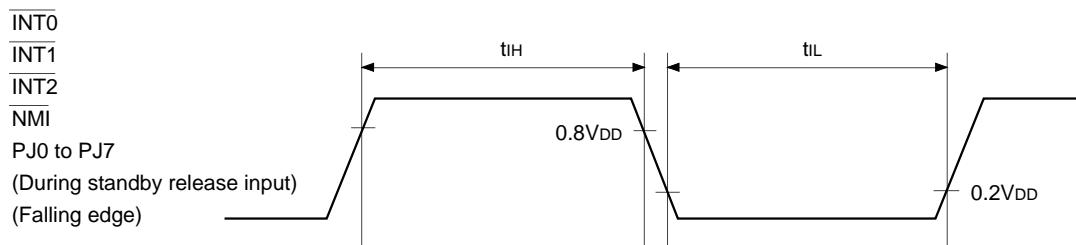
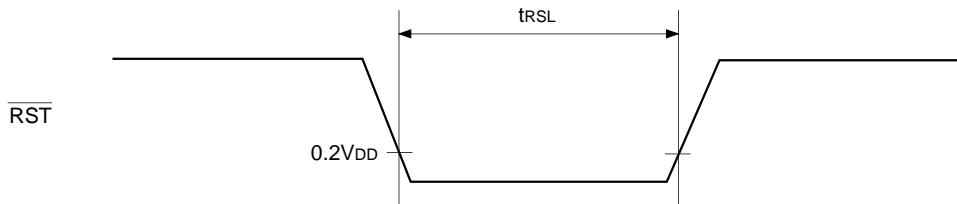


Fig. 8. Reset input timing



(5) Others

(Ta = -20 to +75°C, VDD = 3.0 to 5.5V, Vss = 0V)

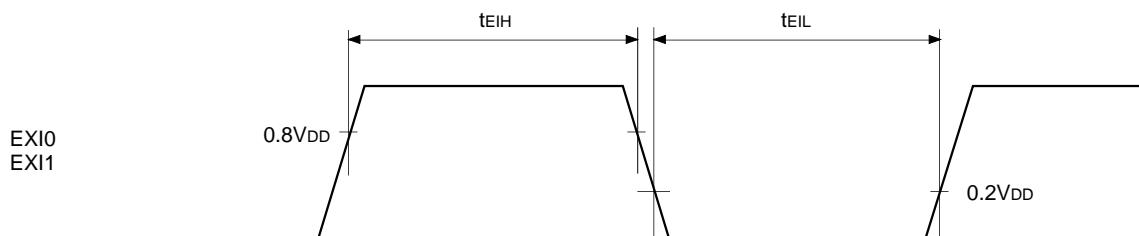
Item	Symbol	Pin	Condition	Min.	Max.	Unit
EXI input high and low level width	tEIH tEIL	EXI0 EXI1	tsys = 2000/fc	tsys + 200		ns

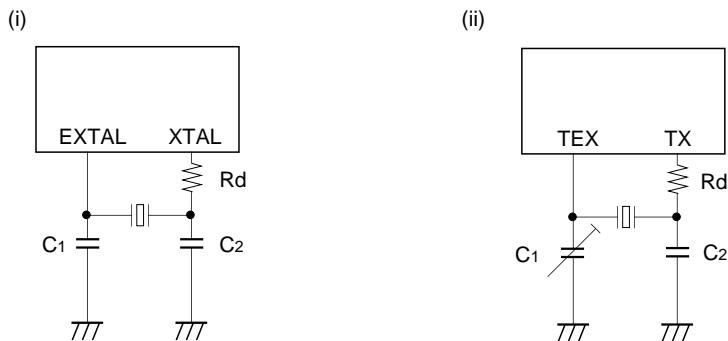
Note) tsys indicates three values according to the contents of the clock control register (address; 00FEH)
upper 2 bits (CPU clock selection).

tsys [ns] = 2000/fc (Upper 2-bit = "00"), 4000/fc (Upper 2-bit = "01"), 16000/fc (Upper 2-bit = "11")

tFRC [ns] = 1000/fc

Fig. 9. Other timings



Supplement**Fig. 10. Recommended oscillation circuit**

Manufacturer	Model	fc (MHz)	C1 (pF)	C2 (pF)	Rd (Ω)	Circuit example		
RIVER ELETEC CO., LTD.	HC-49/U03	8.00	10	10	0	(i)		
		10.00						
		12.00	5	5				
		16.00						
KINSEKI LTD.	HC-49/U (-S)	8.00	16	12	0	(i)		
		10.00	16	12				
		12.00	12	12				
		16.00	12	12				
	P3	32.768kHz	30	18	470k	(ii)		

Those marked with an asterisk (*) signify types with built-in ground capacitance (C1, C2).

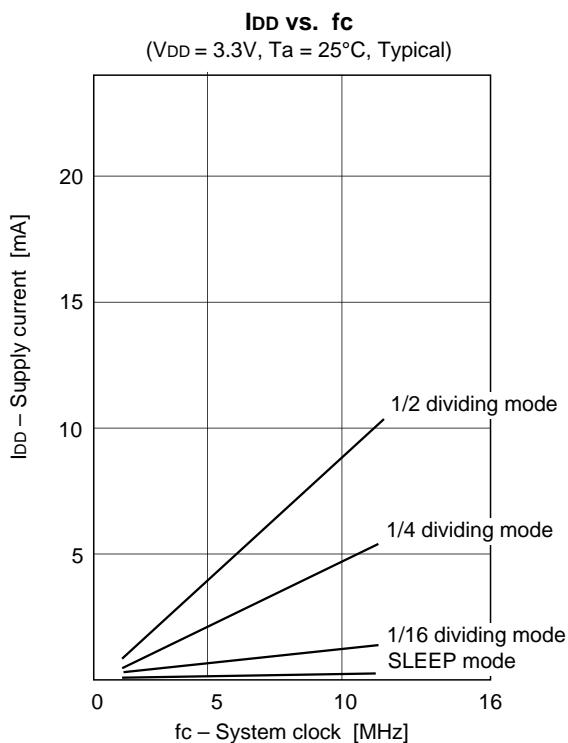
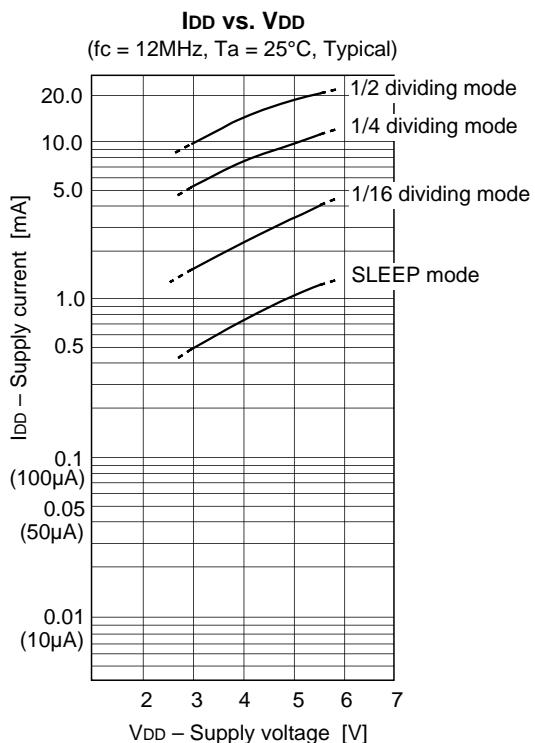
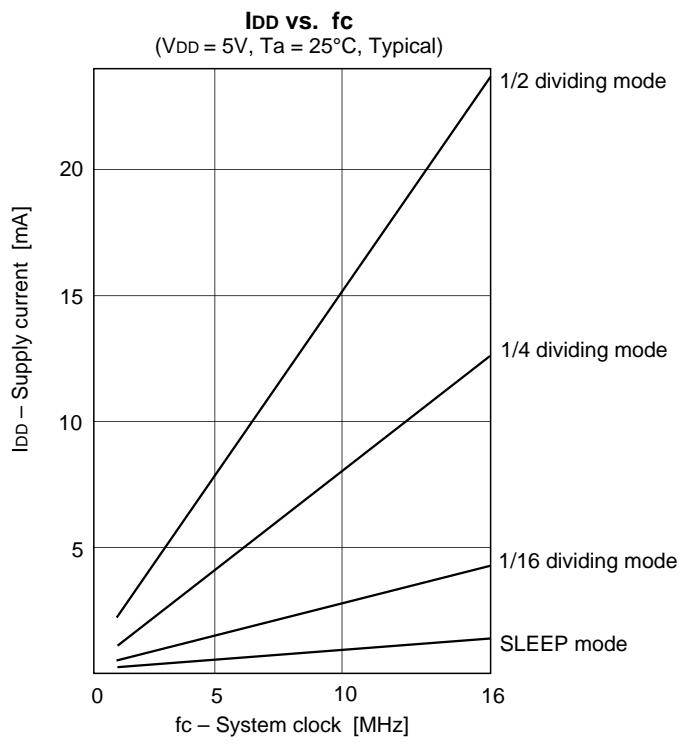
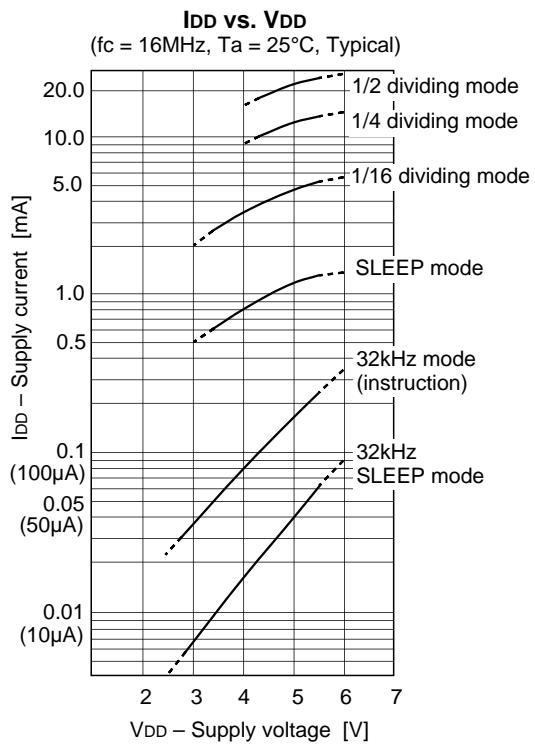
Mask option table

Item	Content	
Reset pin pull-up resistor	Non-existent	Existen
Input circuit format*	CMOS schmitt	TTL schmitt

* The input circuit format can be selected each for PG4 pin and PG5 pin.

However, TTL schmitt can not be selected when the supply voltage (V_{DD}) ranges from 3.0V to 5.5V.

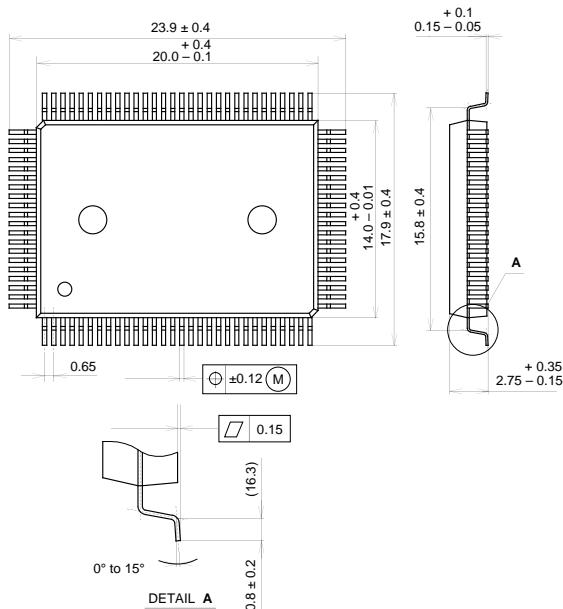
Characteristics Curve



Package Outline

Unit: mm

100PIN QFP (PLASTIC)

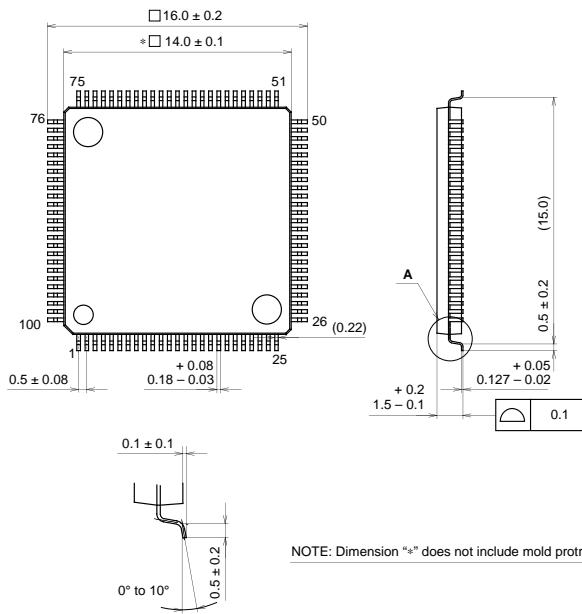


PACKAGE STRUCTURE

SONY CODE	QFP-100P-L01
EIAJ CODE	*QFP100-P-1420-A
JEDEC CODE	-----

PACKAGE MATERIAL	EPOXY RESIN
LEAD TREATMENT	SOLDER PLATING
LEAD MATERIAL	COPPER / 42 ALLOY
PACKAGE WEIGHT	1.4g

100PIN LQFP (PLASTIC)



DETAIL A

SONY CODE	LQFP-100P-L01
EIAJ CODE	*QFP100-P-1414-A
JEDEC CODE	-----

PACKAGE STRUCTURE

PACKAGE MATERIAL	EPOXY/PHENOL RESIN
LEAD TREATMENT	SOLDER PLATING
LEAD MATERIAL	42 ALLOY
PACKAGE WEIGHT	-----